

Dual, Low Noise, Single-Supply Variable Gain Amplifier

AD605

FEATURES

2 independent linear-in-dB channels Input noise at maximum gain: 1.8 nV/√Hz, 2.7 pA/√Hz Bandwidth: 40 MHz (-3 dB) Differential input Absolute gain range programmable -14 dB to +34 dB (FBK shorted to OUT) through 0 dB to 48 dB (FBK open) Variable gain scaling: 20 dB/V through 40 dB/V Stable gain with temperature and supply variations Single-ended unipolar gain control Output common mode independently set Power shutdown at lower end of gain control Single 5 V supply Low power: 90 mW/channel Drives ADCs directly

APPLICATIONS

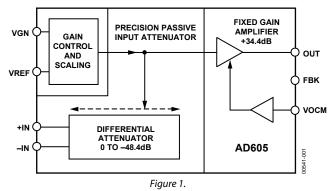
Ultrasound and sonar time-gain controls High performance AGC systems Signal measurement

GENERAL DESCRIPTION

The AD605 is a low noise, accurate, dual-channel, linear-in-dB variable gain amplifier (VGA), optimized for any application requiring high performance, wide bandwidth variable gain control. Operating from a single 5 V supply, the AD605 provides differential inputs and unipolar gain control for ease of use. Added flexibility is achieved with a user-determined gain range and an external reference input that provide user-determined gain scaling (dB/V).

The high performance linear-in-dB response of the AD605 is achieved with the differential input, single-supply, exponential amplifier (DSX-AMP) architecture. Each of the DSX-AMPs comprises a variable attenuator of 0 dB to -48.4 dB followed by a high speed, fixed-gain amplifier. The attenuator is based on a 7-stage R-1.5R ladder network. The attenuation between tap points is 6.908 dB, and 48.360 dB for the entire ladder network. The DSX-AMP architecture results in 1.8 nV/ $\sqrt{\text{Hz}}$ input noise spectral density and accepts a ±2.0 V input signal when VOCM is biased at VP/2.

FUNCTIONAL BLOCK DIAGRAM



Each independent channel of the AD605 provides a gain range of 48 dB that can be optimized for the application. Gain ranges between -14 dB to +34 dB and 0 dB to +48 dB can be selected by a single resistor between Pin FBK and Pin OUT. The lower and upper gain ranges are determined by shorting Pin FBK to Pin OUT or leaving Pin FBK unconnected, respectively. The two channels of the AD605 can be cascaded to provide 96 dB of very accurate gain range in a monolithic package.

The gain control interface provides an input resistance of approximately 2 M Ω and scale factors from 20 dB/V to 30 dB/V for a VREF input voltage of 2.5 V to 1.67 V, respectively. Note that scale factors up to 40 dB/V are achievable with reduced accuracy for scales above 30 dB/V. The gain scales linearly in dB with control voltages (VGN) of 0.4 V to 2.4 V for the 20 dB/V scale and 0.20 V to 1.20 V for the 40 dB/V scale. When VGN is <50 mV, the amplifier is powered down to draw 1.9 mA. Under normal operation, the quiescent supply current of each amplifier channel is only 18 mA.

The AD605 is available in a 16-lead PDIP and a 16-lead SOIC_N package and is guaranteed for operation over the -40° C to $+85^{\circ}$ C temperature range.

Rev. F

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

SPECIFICATIONS

Each channel @ $T_A = 25^{\circ}C$, $V_S = 5 V$, $R_S = 50 \Omega$, $R_L = 500 \Omega$, $C_L = 5 pF$, $V_{REF} = 2.5 V$ (scaling = 20 dB/V), -14 dB to +34 dB gain range, unless otherwise noted.

Table 1.

		AD605A				AD605B		
Parameter	Conditions	Min	Тур	Max	Min	Тур	Мах	Unit
INPUT CHARACTERISTICS								
Input Resistance			175 ± 40			175 ± 40		Ω
Input Capacitance			3.0			3.0		pF
Peak Input Voltage	At minimum gain		2.5 ± 2.5			2.5 ± 2.5		V
Input Voltage Noise	VGN = 2.9 V		1.8			1.8		nV/√Hz
Input Current Noise	VGN = 2.9 V		2.7			2.7		pA/√Hz
Noise Figure	$R_s = 50 \Omega$, $f = 10 MHz$, VGN = 2.9 V		8.4			8.4		dB
	$R_s = 200 \Omega$, $f = 10 MHz$, VGN = 2.9 V		12			12		dB
Common-Mode Rejection Ratio	f = 1 MHz, VGN = 2.65 V		-20			-20		dB
OUTPUT CHARACTERISTICS								
–3 dB Bandwidth	Constant with gain		40			40		MHz
Slew Rate	VGN = 1.5 V, output = 1 V step		170			170		V/µs
Output Signal Range	$R_L \ge 500 \Omega$		2.5 ± 1.5			2.5 ± 1.5		V
Output Impedance	f = 10 MHz		2			2		Ω
Output Short-Circuit Current			±40			±40		mA
Harmonic Distortion	VGN = 1 V, V _{OUT} = 1 V p-p							
HD2	f = 1 MHz		-64			-64		dBc
HD3	f = 1 MHz		-68			-68		dBc
HD2	f = 10 MHz		-51			-51		dBc
HD3	f = 10 MHz		-53			-53		dBc
Two-Tone Intermodulation Distortion (IMD)	$R_s = 0 \Omega$, VGN = 2.9 V, V _{OUT} = 1 V p-p							
	f = 1 MHz		-72			-72		dBc
	f = 10 MHz		-60			-60		dBc
1 dB Compression Point	f = 10 MHz, VGN = 2.9 V, output referred		15			15		dBm
Third-Order Intercept	f = 10 MHz, VGN = 2.9 V,		-1			-1		dBm
	V _{OUT} = 1 V p-p, input referred							
Channel-to-Channel Crosstalk	Ch1: VGN = 2.65 V, inputs shorted, Ch2: VGN = 1.5 V (mid gain), $f = 1 MHz$, $V_{OUT} = 1 V p-p$		-70			-70		dB
Group Delay Variation	1 MHz < f < 10 MHz, full gain range		±2.0			±2.0		ns
VOCM Input Resistance			45			45		kΩ
ACCURACY								
Absolute Gain Error								
–14 dB to –11 dB	0.25 V < VGN < 0.40 V	-1.2	+1.0	+3.0	-1.2	+0.75	+3.0	dB
-11 dB to +29 dB	0.40 V < VGN < 2.40 V	-1.0	±0.3	+1.0	-1.0	±0.2	+1.0	dB
+29 dB to +34 dB	2.40 V < VGN < 2.65 V	-3.5	-1.25	+1.2	-3.5	-1.25	+1.2	dB
Gain Scaling Error	0.4 V < VGN < 2.4 V		±0.25			±0.25		dB/V
Output Offset Voltage	$V_{\text{RFF}} = 2.500 \text{ V}, \text{ VOCM} = 2.500 \text{ V}$	-30	±20	+30	-30	±20	+30	mV
Output Offset Variation	$V_{REF} = 2.500 \text{ V}, \text{VOCM} = 2.500 \text{ V}$		30	57		30	50	mV

AD605

			AD605A		AD605B			<u> </u>
Parameter	Conditions	Min	Тур	Max	Min	Тур	Max	Unit
GAIN CONTROL INTERFACE						·		
Gain Scaling Factor	$V_{REF} = 2.5 V$, $0.4 V < VGN < 2.4 V$	19	20	21	19	20	21	dB/V
	$V_{REF} = 1.67 V$		30			30		dB/V
Gain Range	FBK short to OUT		-14 to +34			-14 to +34		dB
	FBK open		0 to 48			0 to 48		dB
Input Voltage (VGN) Range	20 dB/V, VREF = 2.5 V		0.1 to 2.9			0.1 to 2.9		v
Input Bias Current			-0.4			-0.4		μA
Input Resistance			2			2		MΩ
Response Time	48 dB gain change		0.2			0.2		μs
POWER SUPPLY								
Supply Voltage		4.5	5.0	5.5	4.5	5.0	5.5	v
Power Dissipation			90			90		mW
VREF Input Resistance			10			10		kΩ
Quiescent Supply Current	VPOS		18	23		18	23	mA
Power-Down	VPOS, VGN < 50 mV		1.9	3.0		1.9	3.0	mA
Power-Up Response Time	48 dB gain, $V_{OUT} = 2 V p-p$		0.6			0.6		μs
Power-Down Response Time			0.4			0.4		μs

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating		
Supply Voltage +Vs			
Pin 12, Pin 13 (with Pin 4, Pin 5 = 0 V)	6.5 V		
Input Voltage Pin 1 to Pin 3, Pin 6 to Pin 9, Pin 16	VPOS, 0 V		
Internal Power Dissipation			
16-Lead PDIP	1.4 W		
16-Lead SOIC_N	1.2 W		
Operating Temperature Range	-40°C to +85°C		
Storage Temperature Range	-65°C to +150°C		
Lead Temperature, Soldering 60 sec	300°C		
Thermal Resistance θ _{JA}			
16-Lead PDIP	85°C/W		
16-Lead SOIC_N	100°C/W		

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

AD605

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

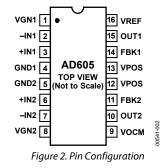
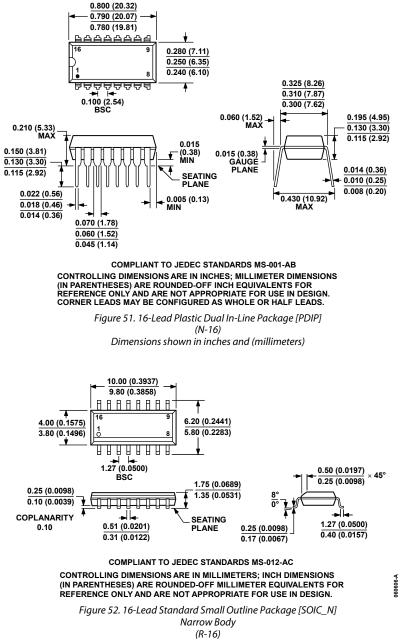


Table 3. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	VGN1	CH1 Gain Control Input and Power-Down Pin. If grounded, device is off; otherwise, positive voltage increases gain.
2	-IN1	CH1 Negative Input.
3	+IN1	CH1 Positive Input.
4	GND1	Ground.
5	GND2	Ground.
6	+IN2	CH2 Positive Input.
7	–IN2	CH2 Negative Input.
8	VGN2	CH2 Gain Control Input and Power-Down Pin. If grounded, device is off; otherwise, positive voltage increases gain.
9	VOCM	Input to This Pin Defines Common-Mode Voltage for OUT1 and OUT2.
10	OUT2	CH2 Output.
11	FBK2	Feedback Pin That Selects Gain Range of CH2.
12	VPOS	Positive Supply.
13	VPOS	Positive Supply.
14	FBK1	Feedback Pin That Selects Gain Range of CH1.
15	OUT1	CH1 Output.
16	VREF	Input to This Pin Sets Gain Scaling for Both Channels: $2.5 V = 20 \text{ dB/V}$ and $1.67 V = 30 \text{ dB/V}$.

073106-B

OUTLINE DIMENSIONS



Dimensions shown in millimeters and (inches)

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD605AN	-40°C to +85°C	16-Lead PDIP	N-16
AD605ANZ ¹	-40°C to +85°C	16-Lead PDIP	N-16
AD605AR	-40°C to +85°C	16-Lead SOIC_N	R-16
AD605AR-REEL	-40°C to +85°C	16-Lead SOIC_N, 13" Tape and Reel	R-16
AD605AR-REEL7	-40°C to +85°C	16-Lead SOIC_N, 7" Tape and Reel	R-16
AD605ARZ ¹	-40°C to +85°C	16-Lead SOIC_N	R-16
AD605ARZ-RL ¹	-40°C to +85°C	16-Lead SOIC_N, 13" Tape and Reel	R-16
AD605ARZ-R71	-40°C to +85°C	16-Lead SOIC_N, 7" Tape and Reel	R-16
AD605BN	-40°C to +85°C	16-Lead PDIP	N-16
AD605BR	-40°C to +85°C	16-Lead SOIC_N	R-16
AD605BR-REEL	-40°C to +85°C	16-Lead SOIC_N, 13" Tape and Reel	R-16
AD605BR-REEL7	-40°C to +85°C	16-Lead SOIC_N, 7" Tape and Reel	R-16
AD605BRZ ¹	-40°C to +85°C	16-Lead SOIC_N	R-16
AD605BRZ-RL ¹	-40°C to +85°C	16-Lead SOIC_N, 13" Tape and Reel	R-16
AD605BRZ-R71	-40°C to +85°C	16-Lead SOIC_N, 7" Tape and Reel	R-16
AD605-EVALZ ¹		Evaluation Board	
AD605ACHIPS		DIE	

¹ Z = RoHS Compliant Part.